# 74HC390; 74HCT390

## **Dual decade ripple counter**

Rev. 6 — 19 March 2024

Product data sheet

### 1. General description

The 74HC390; 74HCT390 is a dual 4-bit decade ripple counter divided into four separately clocked sections. The counters have two divide-by-2 sections and two divide-by-5 sections. These sections share an asynchronous master reset input (nMR) and can be used in a BCD decade or bi-quinary configuration. If master reset inputs (1MR and 2MR) are used to simultaneously clear all 8 bits of the counter, a number of counting configurations are possible within one package. The separate clocks (n $\overline{CP0}$  and n $\overline{CP1}$ ) of each section allow ripple counter or frequency division applications of divide-by-2, 4, 5, 10, 20, 25, 50 or 100. Each section is triggered by the HIGH-to-LOW transition of the clock inputs (n $\overline{CP0}$  and n $\overline{CP1}$ ). For BCD decade operation, the nQ0 output is connected to the n $\overline{CP1}$  input of the divide-by-5 section. For bi-quinary decade operation, the nQ3 output is connected to the n $\overline{CP0}$  input and nQ0 becomes the decade output. A HIGH on the nMR input overrides the clocks and sets the four outputs LOW. This device features reduced input threshold levels to allow interfacing to TTL logic levels. Inputs also include clamp diodes, this enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

### 2. Features and benefits

- Input levels:
  - For 74HC390: CMOS level
  - For 74HCT390: TTL level
- · Two BCD decade or bi-quinary counters
- One device can be configured to divide-by-2, 4, 5, 10, 20, 25, 50 or 100
- Two master reset inputs to clear each decade counter individually
- Supply voltage range from 4.5 V to 5.5 V
- · High noise immunity
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standard JESD7A (4.5 V to 5.5 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 2 exceeds 2000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

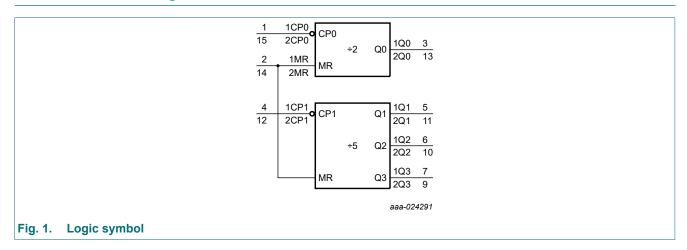
## 3. Ordering information

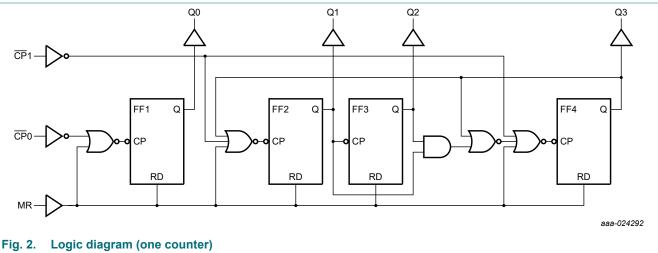
**Table 1. Ordering information** 

Type number	Package										
	Temperature range	Name	Description	Version							
74HC390D	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1							
74HCT390D			body width 3.9 mm								
74HC390PW	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads;	SOT403-1							
74HCT390PW			body width 4.4 mm								



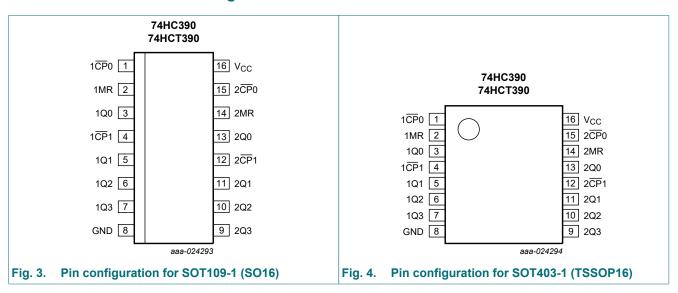
## 4. Functional diagram





## 5. Pinning information

### 5.1. Pinning



### 5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description			
1 <del>CP</del> 0, 2 <del>CP</del> 0	1, 15	clock input divide-by-2 section (HIGH-to-LOW; edge-triggered)			
1MR, 2MR	2, 14	asynchronous master reset input (active HIGH)			
1Q0, 1Q1, 1Q2, 1Q3	3, 5, 6, 7	flip-flop outputs			
1CP1, 2CP1	4, 12	clock input divide-by-5 section (HIGH-to-LOW; edge-triggered)			
GND	8	ground (0 V)			
2Q0, 2Q1, 2Q2, 2Q3	13, 11, 10, 9	flip-flop outputs			
V <sub>CC</sub>	16	supply voltage			

## 6. Functional description

### Table 3. BCD count sequence

Output nQ0 connected to  $n\overline{CP}1$ ; counter input on  $n\overline{CP}0$ ;

H = HIGH voltage level; L = LOW voltage level

Count	Output	<b>Dutput</b>							
	nQ0	nQ1	nQ2	nQ3					
0	L	L	L	L					
1	Н	L	L	L					
2	L	Н	L	L					
3	Н	Н	L	L					
4	L	L	Н	L					
5	Н	L	Н	L					
6	L	Н	Н	L					
7	Н	Н	Н	L					
8	L	L	L	Н					
9	Н	L	L	Н					

### Table 4. Bi-quinary count sequence

Output nQ3 connected to  $n\overline{CP}0$ ; counter input on  $n\overline{CP}1$ ;

H = HIGH voltage level; L = LOW voltage level

Count	Output			
	nQ0	nQ1	nQ2	nQ3
0	L	L	L	L
1	L	Н	L	L
2	L	L	Н	L
3	L	Н	Н	L
4	L	L	L	Н
5	Н	L	L	L
6	Н	Н	L	L
7	Н	L	Н	L
8	Н	Н	Н	L
9	Н	L	L	Н

## 7. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I <sub>O</sub>	output current	-0.5 V < V <sub>O</sub> < V <sub>CC</sub> + 0.5 V	-	±25	mA
I <sub>CC</sub>	supply current		-	+50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	[1]	-	500	mW

<sup>[1]</sup> For SOT109-1 (SO16) package:  $P_{tot}$  derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package:  $P_{tot}$  derates linearly with 8.5 mW/K above 91 °C.

## 8. Recommended operating conditions

### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC390		74HCT390			Unit
			Min	Тур	Max	Min	Тур	Max	
$V_{CC}$	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 2.0 V	-	-	625	-	-	-	ns/V
		V <sub>CC</sub> = 4.5 V	-	1.67	139	-	1.67	139	ns/V
		V <sub>CC</sub> = 6.0 V	-	-	83	-	-	-	ns/V

### 9. Static characteristics

### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
74HC39	0									
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	1.2	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 4.5 V	3.15	2.4	-	3.15	-	3.15	-	V
		V <sub>CC</sub> = 6.0 V	4.2	3.2	-	4.2	-	4.2	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	0.8	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 4.5 V	-	2.1	1.35	-	1.35	-	1.35	V
		V <sub>CC</sub> = 6.0 V	-	2.8	1.8	-	1.8	-	1.8	V

Symbol	Parameter	Conditions		25 °C			°C to 5 °C	-40 °C to +125 °C		Unit
			Min	Тур	Max	Min	Max	Min	Max	
V <sub>OH</sub>	HIGH-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 6.0 V	5.9	6.0	-	5.9	-	5.9	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 4.5 V	3.98	4.32	-	3.84	-	3.7	-	V
		I <sub>O</sub> = -5.2 mA; V <sub>CC</sub> = 6.0 V	5.48	5.81	-	5.34	-	5.2	-	V
V <sub>OL</sub>	LOW-level	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 6.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 4.5 V	-	0.15	0.26	-	0.33	-	0.4	V
		I <sub>O</sub> = 5.2 mA; V <sub>CC</sub> = 6.0 V	-	0.16	0.26	-	0.33	-	0.4	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	-	-	pF
74HCT3	90		1	'	·	'		l	'	
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	1.6	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	1.2	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = -20 μA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = -4.0 mA	3.98	4.32	-	3.84	-	3.7	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$								
	output voltage	I <sub>O</sub> = 20 μA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 5.5 V	-	0.15	0.26	-	0.33	-	0.4	V
l <sub>l</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	±0.1	-	±1	-	±1	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	8.0	-	80	-	160	μΑ
ΔI <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 2.1 \text{ V}$ ; other inputs at $V_{CC}$ or GND; $V_{CC} = 4.5 \text{ V}$ to 5.5 V								
		nCP0 inputs	-	45	162	-	202.5	-	220.5	μΑ
		nCP1, nMR inputs	-	60	216	-	270	-	294	μΑ
Cı	input capacitance		-	3.5	-	-	-	-	-	pF

## 10. Dynamic characteristics

#### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V);  $C_L$  = 50 pF unless otherwise specified; for test circuit, see Fig. 7.

Symbol	Parameter	Conditions		25 °C			°C to 5 °C		°C to 5 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
74HC390	)									
t <sub>pd</sub>	propagation	nCP0 to nQ0; see Fig. 5 [2]								
	delay	V <sub>CC</sub> = 2.0 V	-	47	145	-	180	-	220	ns
		V <sub>CC</sub> = 4.5 V	-	17	29	-	36	-	44	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	14	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	25	-	31	-	38	ns
		nCP1 to nQ1; see Fig. 5								
		V <sub>CC</sub> = 2.0 V	-	50	155	-	195	-	235	ns
		V <sub>CC</sub> = 4.5 V	-	18	31	-	39	-	47	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	15	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	26	-	33	-	40	ns
		nCP1 to nQ2; see Fig. 5								
		V <sub>CC</sub> = 2.0 V	-	74	210	-	265	-	315	ns
		V <sub>CC</sub> = 4.5 V	-	27	42	-	53	-	63	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	23	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	22	36	-	45	-	54	ns
		nCP1 to nQ3; see Fig. 5								
		V <sub>CC</sub> = 2.0 V	-	50	155	-	195	-	235	ns
		V <sub>CC</sub> = 4.5 V	-	18	31	-	39	-	47	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	15	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	14	26	-	33	-	40	ns
t <sub>PHL</sub>	HIGH to LOW	nMR to nQn; see Fig. 6								
	propagation delay	V <sub>CC</sub> = 2.0 V	-	52	165	-	205	-	250	ns
	delay	V <sub>CC</sub> = 4.5 V	-	19	33	-	41	-	50	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	16	-	-	-	-	-	ns
		V <sub>CC</sub> = 6.0 V	-	15	28	-	35	-	43	ns
t <sub>t</sub>	transition time	nQn; see Fig. 5 [3]								
		V <sub>CC</sub> = 2.0 V	-	19	75	-	95	-	110	ns
		V <sub>CC</sub> = 4.5 V	-	7	15	-	19	-	22	ns
		V <sub>CC</sub> = 6.0 V	-	6	13	-	16	-	19	ns

Symbol	Parameter	Conditions		25 °C			°C to		°C to 5 °C	Unit
			Min	Typ [1]	Max	Min	Max	Min	Max	
t <sub>W</sub>	pulse width	nCP0, nCP1; HIGH or LOW; see Fig. 5								
		V <sub>CC</sub> = 2.0 V	80	19	-	100	-	120	-	ns
		V <sub>CC</sub> = 4.5 V	16	7	-	20	-	24	-	ns
		V <sub>CC</sub> = 6.0 V	14	6	-	17	-	20	-	ns
		nMR HIGH; see Fig. 6								
		V <sub>CC</sub> = 2.0 V	80	28	-	105	-	130	-	ns
		V <sub>CC</sub> = 4.5 V	17	10	-	21	-	26	-	ns
		V <sub>CC</sub> = 6.0 V	14	8	-	18	-	22	-	ns
t <sub>rec</sub>	recovery time	nMR to nCPn; see Fig. 6								
		V <sub>CC</sub> = 2.0 V	75	22	-	95	-	110	-	ns
		V <sub>CC</sub> = 4.5 V	15	8	-	19	-	22	-	ns
		V <sub>CC</sub> = 6.0 V	13	6	-	16	-	19	-	ns
f <sub>max</sub>	maximum	nCPn; see Fig. 5								
	frequency	V <sub>CC</sub> = 2.0 V	6.0	20	-	4.8	-	4.0	-	MHz
		V <sub>CC</sub> = 4.5 V	30	60	-	24	-	20	-	MHz
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	66	-	-	-	-	-	MHz
		V <sub>CC</sub> = 6.0 V	35	71	-	28	-	24	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$C_L$ = 50 pF; f = 1 MHz; [4] $V_I$ = GND to $V_{CC}$	-	20	-	-	-	-	-	pF
74HCT3	90									
t <sub>pd</sub>	propagation	nCP0 to nQ0; see Fig. 5 [2]								
	delay	V <sub>CC</sub> = 4.5 V	-	21	34	-	43	-	51	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	18	-	-	-	-	-	ns
		nCP1 to nQ1; see Fig. 5								
		V <sub>CC</sub> = 4.5 V	-	22	38	-	48	-	57	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	19	-	-	-	-	-	ns
		nCP1 to nQ2; see Fig. 5								
		V <sub>CC</sub> = 4.5 V	-	30	51	-	64	-	77	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	26	-	-	-	-	-	ns
		nCP1 to nQ3; see Fig. 5								
		V <sub>CC</sub> = 4.5 V	-	22	38	-	48	-	57	ns
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	19	-	-	-	-	-	ns
t <sub>PHL</sub>	HIGH to LOW	nMR to nQn; see Fig. 6								
	propagation	V <sub>CC</sub> = 4.5 V	-	21	36	-	45	-	54	ns
	delay	V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	18	-	-	-	-	-	ns
t <sub>t</sub>	transition time	nQn; see Fig. 5 [3]								+
		V <sub>CC</sub> = 4.5 V	_	7	15	_	19	_	22	ns

Symbol	Parameter	Conditions	25 °C		-40 °C to +85 °C		-40 °C to +125 °C		Unit	
			Min	Typ [1]	Max	Min	Max	Min	Max	
t <sub>W</sub>	pulse width	nCP0, nCP1; HIGH or LOW; see Fig. 5								
		V <sub>CC</sub> = 4.5 V	18	8	-	23	-	27	-	ns
		nMR HIGH; see Fig. 6								
		V <sub>CC</sub> = 4.5 V	17	10	-	21	-	26	-	ns
t <sub>rec</sub>	recovery time	nMR to nCPn;see Fig. 6								
		V <sub>CC</sub> = 4.5 V	15	8	-	19	-	22	-	ns
f <sub>max</sub>	maximum	nCPn; see Fig. 5								
	frequency	V <sub>CC</sub> = 4.5 V	27	55	-	22	-	18	-	MHz
		V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF	-	61	-	-	-	-	-	MHz
C <sub>PD</sub>	power dissipation capacitance	$C_L = 50 \text{ pF; } f = 1 \text{ MHz;}$ [4] $V_I = \text{GND to } V_{CC} - 1.5 \text{ V}$	-	21	-	-	-	-	-	pF

- All typical values are measured at  $T_{amb}$  = 25 °C.

- [2] t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
   [3] t<sub>t</sub> is the same as t<sub>THL</sub> and t<sub>TLH</sub>.
   [4] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$$
 where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

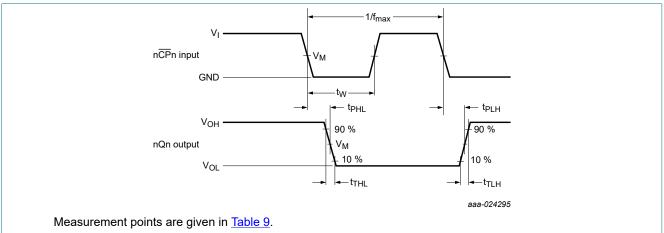
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

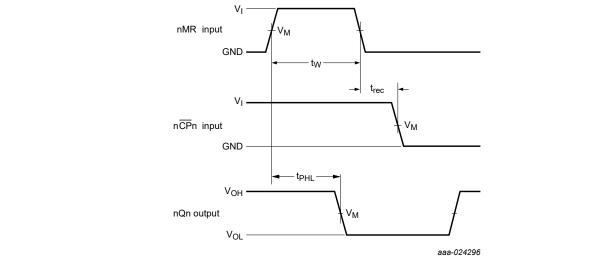
 $\sum (C_L \times V_{CC}^2 \times f_0) = \text{sum of outputs.}$ 

### 10.1. Waveforms and test circuit



V<sub>OL</sub> and V<sub>OH</sub> are typical voltage output levels that occur with the output load.

Fig. 5. The clock input (nCPn) to output (nQn) propagation delays, output transition time, clock pulse width and maximum clock frequency



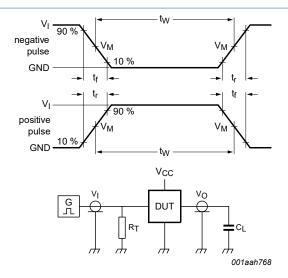
Measurement points are given in Table 9.

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical voltage output levels that occur with the output load.

Fig. 6. The master reset (nMR) pulse width, master reset to output (nQn) propagation delays and master reset to clock (nCPn) recovery time

**Table 9. Measurement points** 

Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74HC390	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74HCT390	1.3 V	1.3 V



Test data is given in Table 10.

Definitions test circuit:

 $R_{T}$  = Termination resistance should be equal to output impedance  $Z_{o}$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

### Fig. 7. Test circuit for measuring switching times

Table 10. Test data

Туре	Input		Load	Test
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	
74HC390	V <sub>CC</sub>	6 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>
74HCT390	3 V	6 ns	15 pF, 50 pF	t <sub>PLH</sub> , t <sub>PHL</sub>

## 11. Package outline

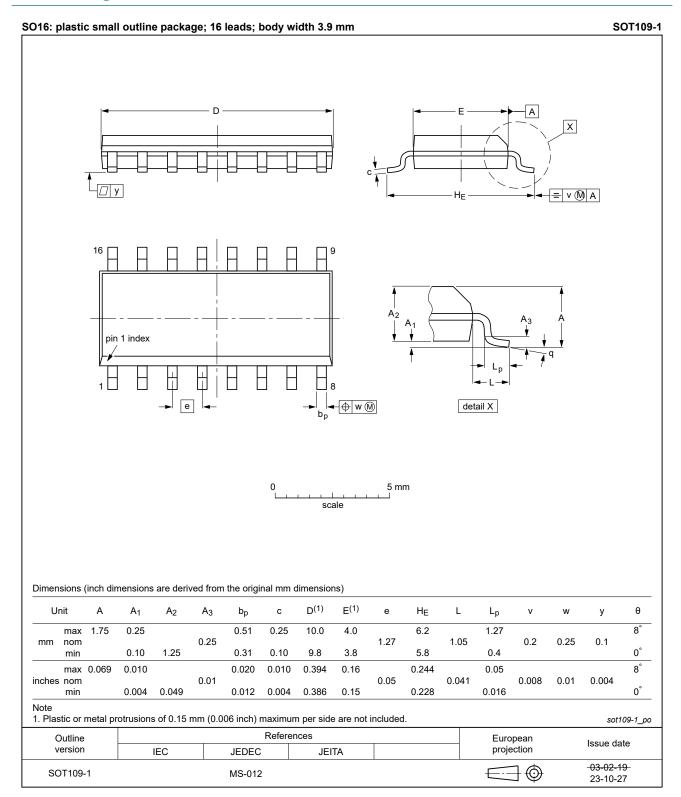


Fig. 8. Package outline SOT109-1 (SO16)

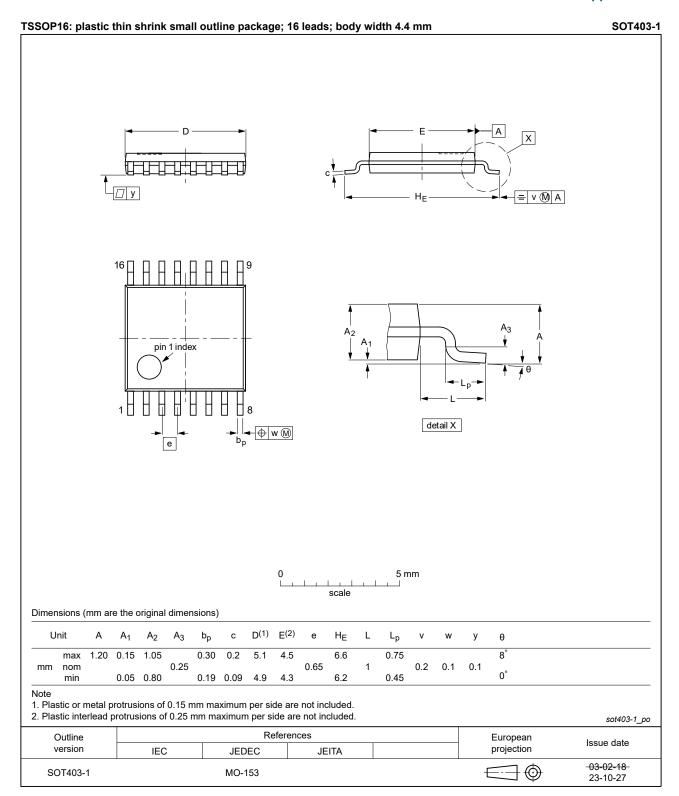


Fig. 9. Package outline SOT403-1 (TSSOP16)

### 12. Abbreviations

#### **Table 11. Abbreviations**

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
TTL	Transistor-Transistor Logic

## 13. Revision history

### Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
74HC_HCT390 v.6	20240319	Product data sheet	-	74HC_HCT390 v.5	
Modifications:	<ul> <li>Fig. 8, Fig. 9: Aligned SO and TSSOP package outline drawings to JEDEC MS-012 and MO-153.</li> <li>Section 2: ESD specification updated according to the latest JEDEC standard.</li> </ul>				
74HC_HCT390 v.5	20211018	Product data sheet	-	74HC_HCT390 v.4	
Modifications:	Type number 74HCT390PW (SOT403-1 / TSSOP16) added.				
74HC_HCT390 v.4	20200821	Product data sheet	-	74HC_HCT390 v.3	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type numbers 74HC390DB and 74HCT390DB (SOT338-1) removed.</li> <li>Table 1: typo corrected.</li> <li>Table 5: Derating values for P<sub>tot</sub> total power dissipation updated.</li> </ul>				
74HC_HCT390 v.3	20160816	Product data sheet	-	74HC_HCT390_CNV v.2	
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> <li>Type numbers 74HC390N and 74HCT390N removed.</li> </ul>				
74HC_HCT390_CNV v.2	19901201	Product specification	-	-	

### 14. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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